

in a comparison gas which is 2% O₂/ 98% N₂. All of the signals were generated with 10 V across the materials, unless otherwise specified. Blank spaces indicate that there was no detectable signal when that gas composition was contacted with that material. Unless otherwise specified, the gases were measured at 2000 ppm in N₂.

Table 5b

Change in temperature in °C

| | AlVO ₄ | BaCuO _{2.5} | Zn ₄ TiO ₆ |
|----------------------|-------------------|----------------------|----------------------------------|
| CO in N ₂ | 18.1 | -6 | 6 |
| N ₂ | 18.1 | -6 | 6 |

Example 6

This example illustrates the use of the AC impedance technique for the measurement of the response of 19 metal oxide semiconducting materials in the presence of 4 gas compositions at 400°C. The signals listed in Table 6 below are the ratios of the magnitudes of the impedances of the materials when exposed to the gas compositions shown to the magnitudes of the impedances in 10,000 ppm O₂ in N₂. The gases used were 200 ppm NO₂ in N₂, 200 ppm NO₂ and 10,000 ppm O₂ in N₂, 1000 ppm CO in N₂, and N₂.

Table 6

| | MgAl ₂ O ₄ | 1% Zn:MgAl ₂ O ₄ | ZnO | WO ₃ | NiFe ₂ O ₄ | SnO ₂ | TiO ₂ |
|--|----------------------------------|--|--------|-----------------|----------------------------------|------------------|------------------|
| NO ₂ in N ₂ | 0.6245 | 0.5544 | 55.85 | 8.772 | 5.008 | 9.243 | 1.536 |
| NO ₂ in O ₂ / N ₂ | 0.7680 | 0.6787 | 47.38 | 9.468 | 12.93 | 10.56 | 1.585 |
| CO in N ₂ | 1.531 | 1.459 | 0.1235 | 0.1865 | 1.248 | 0.0051 | 0.0116 |
| N ₂ | 0.8242 | 0.9219 | 4.1290 | 1.716 | 1.327 | 0.3208 | 1.055 |

| | MnTiO ₃ | NiO | SrNb ₂ O ₆ | CeVO ₄ | 1% Nb:TiO ₂ | FeTiO ₃ | Pr ₆ O ₁₁ |
|--|--------------------|--------|----------------------------------|-------------------|------------------------|--------------------|---------------------------------|
| NO ₂ in N ₂ | 0.8643 | 0.5692 | 1.217 | 0.9847 | 1.937 | 1.299 | 0.5475 |
| NO ₂ in O ₂ / N ₂ | 0.8475 | 0.9662 | 1.228 | 0.9977 | 1.674 | 1.034 | 0.5452 |

| | | | | | | | |
|-------------------------|-------|-------|--------|-------|--------|--------|-------|
| CO in N ₂ | 37.35 | 9.679 | 0.6501 | 1.045 | 0.0112 | 0.6009 | 1.184 |
| N ₂ | 1.264 | 1.257 | 1.011 | 1.001 | 0.8811 | 1.028 | 1.103 |

| | SrTiO ₃ | Ba ₂ Cu ₂ O ₅ | CuMnFe ₂ O ₄ | LaFeO ₃ | Zn ₂ V ₂ O ₇ |
|--|--------------------|--|------------------------------------|--------------------|---|
| NO ₂ in N ₂ | 0.6524 | 0.7869 | 0.9559 | 0.8401 | 1.209 |
| NO ₂ in O ₂ /N ₂ | 0.7596 | 0.7834 | 0.9399 | 0.8506 | 1.114 |
| CO in N ₂ | 0.0178 | 0.7603 | 0.6089 | 2037 | 0.8529 |
| N ₂ | 1.061 | 1.063 | 1.136 | 1.756 | 0.9900 |

Example 7

This example illustrates the use of the AC impedance technique for the measurement of the response of 19 metal oxide semiconducting materials in the presence of 4 gas compositions at 550°C. The signals listed in the table are from the AC impedance technique. The signals are the ratios of the magnitudes of the impedances of the materials when exposed to the gas compositions shown to the magnitudes of the impedances in 10,000 ppm O₂ in N₂. The gases used were 200 ppm NO₂ in N₂, 200 ppm NO₂ & 10,000 ppm O₂ in N₂, 1000 ppm CO in N₂, and N₂.

Table 7

| | MgAl ₂ O ₄ | 1% Zn:MgAl ₂ O ₄ | ZnO | WO ₃ | NiFe ₂ O ₄ | SnO ₂ |
|--|----------------------------------|--|--------|-----------------|----------------------------------|------------------|
| NO ₂ in N ₂ | 0.9894 | 0.9583 | 3.866 | 2.335 | 3.025 | 1.655 |
| NO ₂ in O ₂ /N ₂ | 0.8937 | 0.8984 | 5.272 | 2.006 | 3.553 | 3.390 |
| CO in N ₂ | 1.046 | 0.9697 | 0.0133 | 0.2034 | 0.2506 | 0.0069 |
| N ₂ | 1.067 | 1.060 | 0.7285 | 0.9526 | 1.208 | 0.2666 |

| | TiO ₂ | MnTiO ₃ | NiO | SrNb ₂ O ₆ | CeVO ₄ | 1% Nb:TiO ₂ | FeTiO ₃ |
|--|------------------|--------------------|--------|----------------------------------|-------------------|------------------------|--------------------|
| NO ₂ in N ₂ | 1.135 | 1.010 | 0.9483 | 1.006 | 1.003 | 1.271 | 1.193 |
| NO ₂ in O ₂ /N ₂ | 1.314 | 1.014 | 0.5207 | 1.044 | 0.9975 | 1.302 | 1.073 |
| CO in N ₂ | 0.0017 | 44.00 | 1.194 | 0.2814 | 1.104 | 0.0021 | 0.6743 |
| N ₂ | 0.7263 | 1.280 | 1.341 | 0.9830 | 1.024 | 0.477 | 1.054 |

| | Pr ₆ O ₁₁ | SrTiO ₃ | Ba ₂ Cu ₂ O ₅ | CuMnFe ₂ O ₄ | LaFeO ₃ | Zn ₂ V ₂ O ₇ |
|--|---------------------------------|--------------------|--|------------------------------------|--------------------|---|
| NO ₂ in N ₂ | 1.223 | 0.9055 | 0.7071 | 1.148 | 1.302 | 1.199 |
| NO ₂ in O ₂ / N ₂ | 0.9656 | 0.9881 | 0.3812 | 0.9891 | 0.9429 | 1.086 |
| CO in N ₂ | 62.76 | 0.0029 | 3.0892 | 2.557 | 123.3 | 0.4726 |
| N ₂ | 1.495 | 1.210 | 1.333 | 1.681 | 1.789 | 0.9034 |

Example 8

This example illustrates the use of the AC impedance technique for the measurement of the response of 23 semiconducting materials in the presence of 4 gas compositions at 650-700°C. The signals listed in the table are from the AC impedance technique. The signals are the ratios of the magnitudes of the impedances of the materials when exposed to the gas compositions shown to the magnitudes of the impedances in 10,000 ppm O₂ in N₂. The gases used were 200 ppm NO₂ in N₂, 200 ppm NO₂ & 10,000 ppm O₂ in N₂, 1000 ppm CO in N₂, and N₂.

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Table 8

| | MgAl ₂ O ₄ | 1% Zn:MgAl ₂ O ₄ | ZnO | WO ₃ | NiFe ₂ O ₄ | SnO ₂ | TiO ₂ |
|--|----------------------------------|--|--------|-----------------|----------------------------------|------------------|------------------|
| NO ₂ in N ₂ | 0.9450 | 1.022 | 0.4876 | 0.7151 | 0.5807 | 0.5419 | 0.5617 |
| NO ₂ in O ₂ / N ₂ | 0.6412 | 0.8310 | 1.235 | 1.281 | 1.105 | 0.8265 | 1.030 |
| CO in N ₂ | 0.9074 | 0.9684 | 0.0348 | 0.2693 | 0.0408 | 0.0238 | 0.0015 |
| N ₂ | 1.056 | 1.100 | 0.2753 | 0.6332 | 0.4421 | 0.3521 | 0.3957 |

| | MnTiO ₃ | NiO | SrNb ₂ O ₆ | CeVO ₄ | 1% Nb:TiO ₂ | FeTiO ₃ | Pr ₆ O ₁₁ |
|--|--------------------|--------|----------------------------------|-------------------|------------------------|--------------------|---------------------------------|
| NO ₂ in N ₂ | 1.445 | 1.379 | 0.8852 | 1.050 | 0.5711 | 0.9072 | 1.516 |
| NO ₂ in O ₂ / N ₂ | 0.9561 | 0.8127 | 0.9862 | 1.135 | 0.8263 | 0.9524 | 0.9814 |
| CO in N ₂ | 113.3 | 1.782 | 0.0301 | 1.565 | 0.0035 | 0.4346 | 8005 |
| N ₂ | 1.877 | 1.409 | 0.8788 | 1.080 | 0.2802 | 0.8050 | 1.962 |

| | SrTiO ₃ | Ba ₂ Cu ₂ O ₅ | CuMnFe ₂ O ₄ | LaFeO ₃ | Zn ₂ V ₂ O ₇ |
|-----------------------------------|--------------------|--|------------------------------------|--------------------|---|
| NO ₂ in N ₂ | 1.051 | 0.5615 | 3.401 | 1.331 | 0.8631 |
| NO ₂ in | 0.9320 | 0.9703 | 1.001 | 1.013 | 0.9459 |